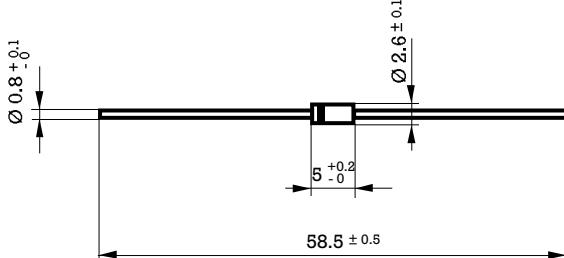


1 Amp. Very Fast Soft Recovery Glass Passivated Avalanche Diode

<p>Dimensions in mm.</p>  <p>DO-41 (Plastic)</p>	<p>Voltage 200 to 1000 V.</p> <p>Current 1 A at 55 °C.</p> <p></p>
<p>Mounting instructions</p> <ol style="list-style-type: none"> Min. distance from body to soldering point, 4 mm. Max. solder temperature, 350 °C. Max. soldering time, 3.5 sec. Do not bend lead at a point closer than 2 mm. to the body. <ul style="list-style-type: none"> • Glass Passivated Junction • High current capability • The plastic material carries U/L recognition 94 V-0 • Terminals: Axial Leads • Polarity: Color band denotes cathode 	

Maximum Ratings, according to IEC publication No. 134

		BYV26A	BYV26B	BYV26C	BYV26D	BYV26E
V_{RRM}	Peak Recurrent reverse voltage (V)	200	400	600	800	1000
V_{RMS}	Maximum RMS voltage	140	280	420	560	700
V_{DC}	Maximum DC blocking voltage	200	400	600	800	1000
$I_{F(AV)}$	Forward current at Tamb = 55 °C				1 A	
I_{FRM}	Recurrent peak forward current				10 A	
I_{FSM}	10 ms. peak forward surge current				30 A	
t_{rr}	Max. reverse recovery time from $I_F = 0.5 \text{ A}$; $I_R = 1 \text{ A}$; $I_{RR} = 0.25 \text{ A}$			30 ns		75 ns
V_{BR}	Avalanche breakdown voltage at 100 μA (V)	>300	>500	>700	>900	>1100
T_j	Operating temperature range				– 65 to + 175 °C	
T_{stg}	Storage temperature range				– 65 to + 175 °C	
E_{RSM}	Maximum non repetitive peak reverse avalanche energy. $I_R = 0.5 \text{ A}$; $T_j = 25 \text{ °C}$				20 mJ	

Electrical Characteristics at Tamb = 25 °C

V_F	Max. forward voltage drop at $I_F = 1 \text{ A}$	at 25 °C	2.5 V
		at 175 °C	1.3 V
I_R	Max. reverse current at V_{RRM}	at 25 °C	5 μA
		at 165 °C	150 μA
R_{thj-a}	Max. thermal resistance ($l = 10 \text{ mm.}$)		50 °C/W

Rating And Characteristic Curves

